

Green Products

10BQ150 SCHOTTKY RECTIFIER

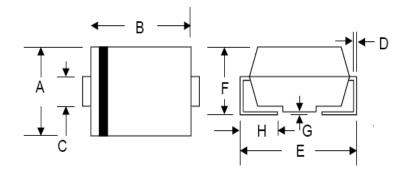
Applications:

- Disk Drives
- · Switching power supply
- Redundant power subsystems
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Battery Charging

Features:

- Small foot print, surface moutable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions: In mm



SMB/DO-214AA					
Dim	Min	Max	Min	Max	
Α	3.30	3.94	0.130	0.155	
В	4.06	4.70	0.160	0.185	
С	1.91	2.11	0.075	0.083	
D	0.152	0.305	0.006	0.012	
E	5.08	5.59	0.2	0.220	
F	2.13	2.44	0.084	0.096	
G	0.051	0.203	0.002	0.008	
Н	0.76	1.27	0.029	0.05	
	in mm		In inch		

OPTION 1

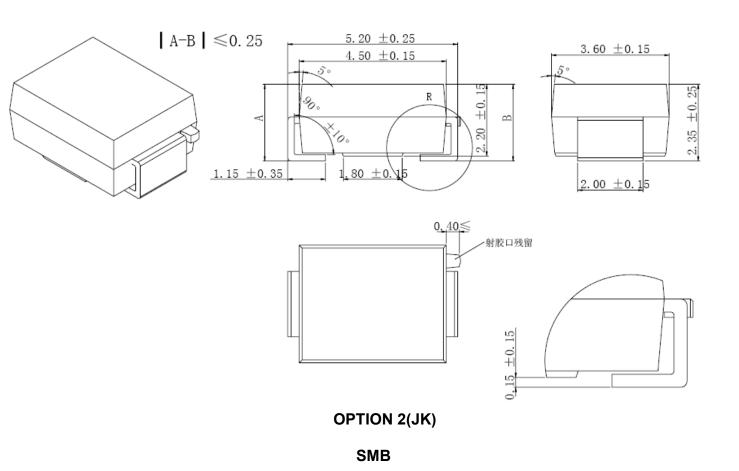
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Marking Diagram:



Where XXXXX is YYWWL

 SB1M
 = Part Name

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
10BQ150	SMB (Pb-Free)	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	150	V
Max. Average Forward Current	I _{F(AV)}	50% duty cycle @T _C =152C, rectangular wave form	1.0	Α
Max. Peak One Cycle Non- Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse	20	А

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Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop*	V_{F1}	@ 1 A, Pulse, T _J = 25 °C	0.86	V
	V_{F2}	@ 1 A, Pulse, T _J = 125 °C	0.70	V
Max. Reverse Current *	I _{R1}	$@V_R = Rated V_R, Pulse, T_J = 25 °C$	0.5	mA
	I _{R2}	$@V_R = Rated V_R, Pulse, T_J = 125 °C$	1	mA
Max. Junction Capacitance	C _T	$@V_R = 5V, T_C = 25 \text{ °C}$ $f_{SIG} = 1MHz$	35	PF
Typical Series Inductance	L _S	Measured lead to lead 5 mm from package body	2.0	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs

 $^{^*}$ Pulse Width < 300 μ s, Duty Cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	T_J	-	-55 to +175	ç
Max. Storage Temperature	T_{stg}	-	-55 to +175	ç
Maximum Thermal Resistance Junction to Lead	$R_{ hetaJL}$	DC operation	36	°C/W
Approximate Weight	wt	-	0.68	g
Case Style		SMB		

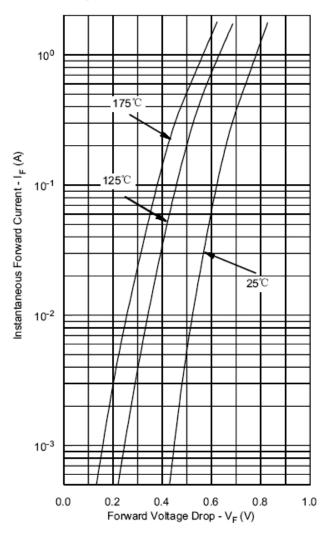
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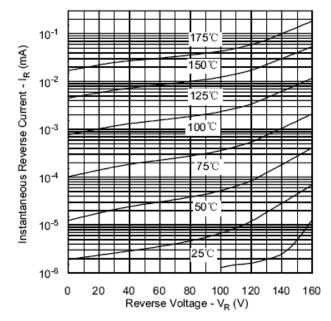


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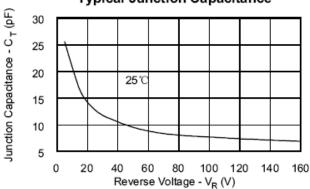
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance



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